



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Inventors: Yukihiro Inoue Art Unit: 2811
Appln. No.: 09/768,556 Examiner: Samuel Gebremariam
Filed: January 25, 2001
For: SEMICONDUCTOR DEVICE

AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action dated December 21, 2001, the Applicant respectfully petitions for a one month extension of time and requests amendment of the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 1-4, without prejudice or disclaimer.

Please amend claims 5-8 to read as follows (Exhibit I contains a marked up version):

5. (Amended) A semiconductor device according to claim 9 wherein said diffusion layer of the first conductivity type is a channel stopper region.

6. (Amended) A semiconductor device according to claim 10 wherein said diffusion layer of the first conductivity type is a

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